

Features

- Low Clamping Voltage
- ESD Protection > 40 KV
- Moisture Sensitivity Level 1
- Epoxy Meets UL 94 V-0 Flammability Rating
- Halogen Free. "Green" Device (Note 1)
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

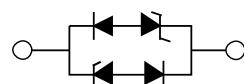
- Operating Junction Temperature Range: -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C

Part Number	Device Marking	
ESDLC3V3D3B	03C	
ESDLC5V0D3B	05C	
ESDLC12VD3B	2C	

Peak Pulse Power (8/20us)	P_{PK}	350W

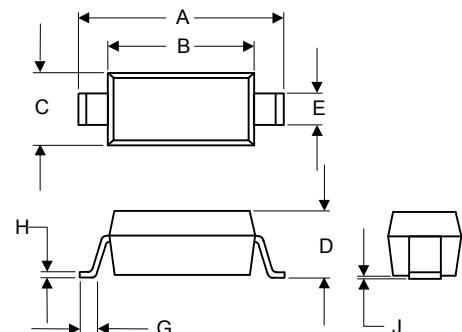
Note: 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Internal Structure



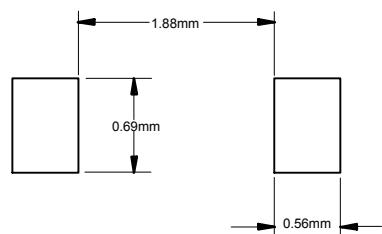
ESD Protection Device

SOD-323



DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	0.090	0.107	2.30	2.70	
B	0.063	0.071	1.60	1.80	
C	0.045	0.053	1.15	1.35	
D	0.031	0.045	0.80	1.15	
E	0.010	0.016	0.25	0.40	
G	0.004	0.018	0.10	0.45	
H	0.004	0.010	0.10	0.25	
J	-----	0.006	-----	0.15	

Suggested Solder Pad Layout



Electrical Characteristics @ 25°C (Unless Otherwise Specified)

ESDLC3V3D3B

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Reverse Working Voltage	V_{RWM}				3.3	V
Reverse Breakdown Voltage	V_{BR}	$I_T = 1\text{mA}$	4			V
Reverse Leakage Current	I_R	$V_{RWM} = 3.3\text{V}$			1	μA
Peak Pulse Current	I_{PP}	$t_p=8/20\mu\text{s}$			28	A
Clamping Voltage	V_C	$I_{PP}=1\text{A}, t_p=8/20\mu\text{s}$			7	V
Clamping Voltage	V_C	$I_{PP}=28\text{A}, t_p=8/20\mu\text{s}$			36	V
Junction Capacitance	C_J	$V_R = 0\text{V}, f = 1\text{MHz}$		4.5		pF

ESDLC5V0D3B

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Reverse Working Voltage	V_{RWM}				5	V
Reverse Breakdown Voltage	V_{BR}	$I_T = 1\text{mA}$	6			V
Reverse Leakage Current	I_R	$V_{RWM} = 5\text{V}$			1	μA
Peak Pulse Current	I_{PP}	$t_p=8/20\mu\text{s}$			21	A
Clamping Voltage	V_C	$I_{PP}=1\text{A}, t_p=8/20\mu\text{s}$			9.8	V
Clamping Voltage	V_C	$I_{PP}=21\text{A}, t_p=8/20\mu\text{s}$			32	V
Junction Capacitance	C_J	$V_R = 0\text{V}, f = 1\text{MHz}$		5		pF

ESDLC12VD3B

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Reverse Working Voltage	V_{RWM}				12	V
Reverse Breakdown Voltage	V_{BR}	$I_T = 1\text{mA}$	13.3			V
Reverse Leakage Current	I_R	$V_{RWM} = 12\text{V}$			1	μA
Peak Pulse Current	I_{PP}	$t_p=8/20\mu\text{s}$			11	A
Clamping Voltage	V_C	$I_{PP}=1\text{A}, t_p=8/20\mu\text{s}$			19	V
Clamping Voltage	V_C	$I_{PP}=11\text{A}, t_p=8/20\mu\text{s}$			28.6	V
Junction Capacitance	C_J	$V_R = 0\text{V}, f = 1\text{MHz}$		3		pF

Curve Characteristics

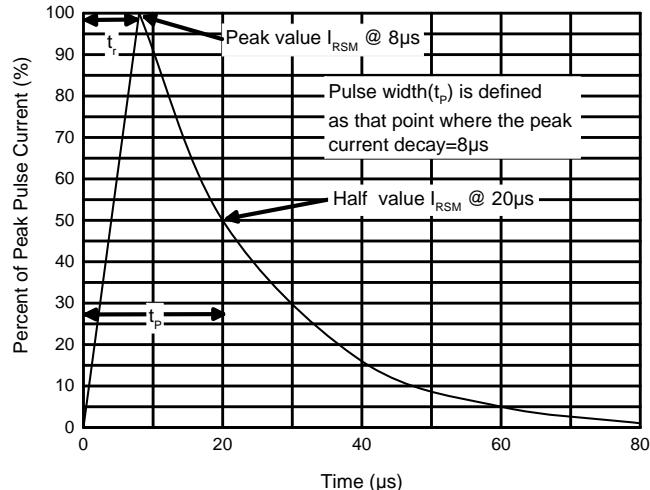
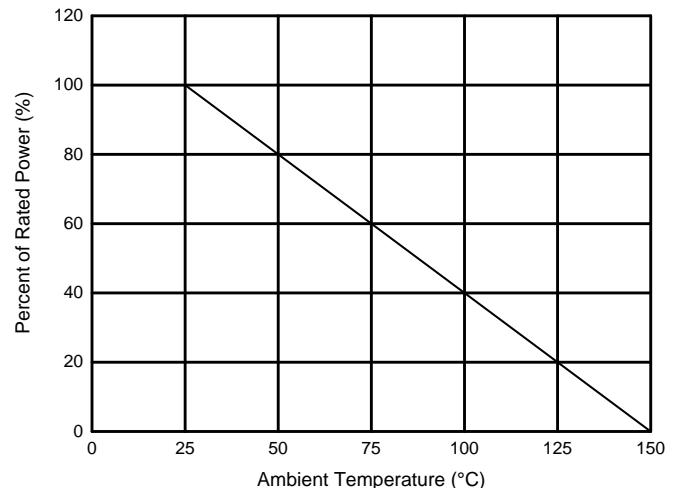
Fig. 1 - 8 X 20 μ s Pulse Waveform

Fig. 2 - Pulse Derating Curve



Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 3Kpcs/Reel